



and narrow size distributions. Another synthesis method of perovskite QDs, room temperature ligand-assisted reprecipitation (LARP) method<sup>6</sup>) and microwave assisted synthesis<sup>7</sup>) have also been reported.

Perovskite QDs have a size dependency of optical properties, which exhibits tunable emission wavelength by size of QDs that smaller size lead to wide energy gap and blue shift due to the quantum size effect, whereas larger size of QDs exhibit a narrow gap and red shift of emission. In order to impart dispersibility in non-polar organic solvents (toluene or octane), long alkyl oleic acid (OA) and oleylamine (OAM) were generally used as surface ligands on perovskite QDs. However, these long alkyl ligands are generally electrical insulating that inhibits a charge injection or transport in the perovskite QD-LEDs. To overcome this issue, we demonstrated the ligand exchange for perovskite QDs via simple post-treatment.<sup>2, 3</sup>) Di-dodecyl dimethyl ammonium bromide (DDAB) consists of relative shorter alkyl chain (C12) with Br<sup>-</sup> anion that lead to facilitate both charge injection or transport and effective surface passivation in perovskite QDs<sup>8</sup>) (Fig.2) Small amount of OA was added into purified CsPbBr<sub>3</sub> QDs dispersion to desorb OAM from QD surface, subsequently DDAB solution in toluene was quickly injected into mixture dispersion under stirring. The average particles size of CsPbBr<sub>3</sub>-DDAB QDs was 9 nm, which was identical sized to the pristine QDs (without ligand exchange). Ligand exchange CsPbBr<sub>3</sub>-DDAB film exhibited a higher PLQY of 42% (FWHM of 19nm) than those of pristine CsPbBr<sub>3</sub> with OA and OAM (15%) due to better surface passivation, although peak emission wavelength and size of particle is almost identical during ligand exchange process. The perovskite QD-LED based on CsPbBr<sub>3</sub>-DDAB exhibited a narrow EL spectra with a FWHM of 17 nm and a very low turn-on voltage of 2.6 V.

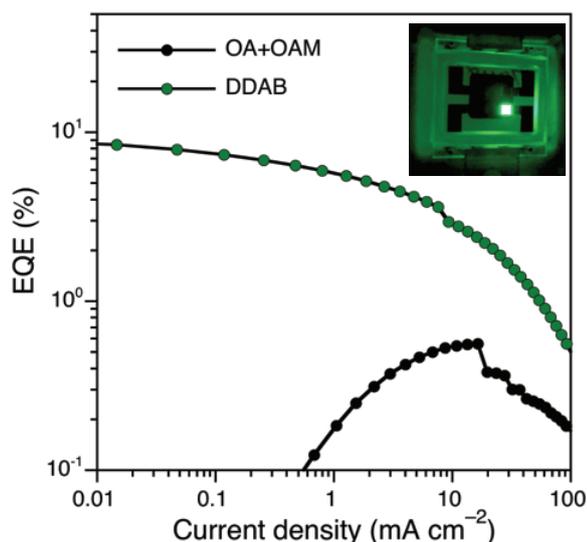


Fig. 3. Ligand exchange for perovskite QDs

The maximum power efficiency and EQE of LED with CsPbBr<sub>3</sub>-DDAB QD reached 31.7 lm/W and the EQE was 8.7% (Fig.3). Control of the interfacial perovskite QDs through ligand removal and energy level alignment in the device structure are promising methods for obtaining high PLQYs in film state and high device efficiency.

### 3 Anion exchange for perovskite QDs

The combination of two different halide anions, mix-halide anion perovskite QDs such as CsPb(Cl/Br)<sub>3</sub> and CsPb(Br/I)<sub>3</sub> can be complemented blue emission (ca. 430–490 nm) and red emission (ca. 550–650 nm) region in visible range by adjustment of mix-halide anion ratio (Fig.4).<sup>1</sup>) The mix-halide perovskite QDs are commonly synthesized by three routes, direct synthesis, blend in QDs, and anion exchange reaction using halide salts (Fig.5). For the direct synthesis method, two type of lead halide salts such as PbCl<sub>2</sub>:PbBr<sub>2</sub> or PbBr<sub>2</sub>:PbI<sub>2</sub> are used in hot-injection synthesis method, which can be easily tuned an optical bandgap and emission wavelength by changing ratio of lead halide salts. On the other hand, post-treatment of synthesized perovskite QDs are also utilized for the form of mix-halide composition due to their high ionic conductive properties. The anion exchange method of perovskite QDs that the replacement halide anion from Br<sup>-</sup> anion to Cl<sup>-</sup> or I<sup>-</sup> anion in perovskite QDs at room temperature demonstrated by Akkerman et al. using various halide salt precursors (ammonium-halides or metal-halide salts) or blended with perovskite QDs dispersion with different halide composition (CsPbCl<sub>3</sub>:CsPbBr<sub>3</sub> or CsPbBr<sub>3</sub>:CsPbI<sub>3</sub>).<sup>9</sup>) The anion exchange perovskite QDs showed a narrow emission with high color purity in full visible range, in a manner similar to directly synthesized perovskite QDs.

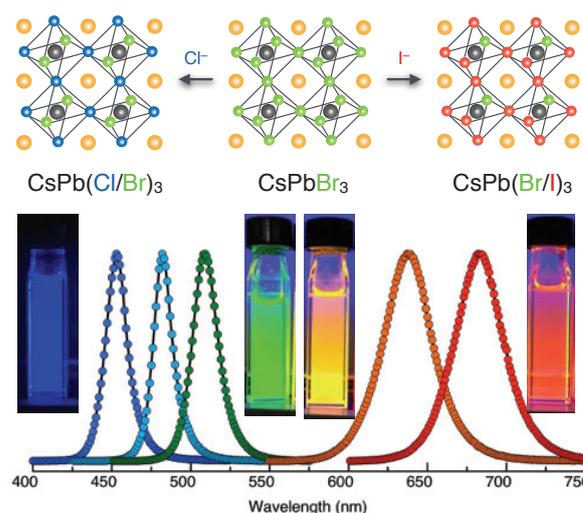


Fig. 4. Mix-halide perovskite QDs

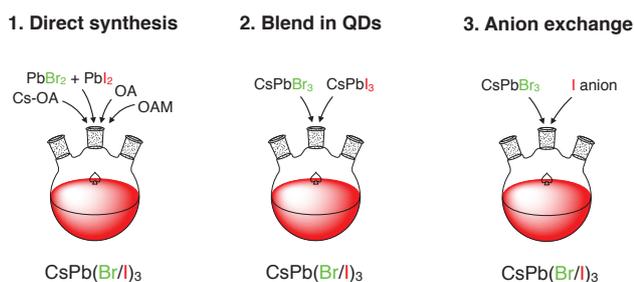


Fig. 5. Synthesis for mix-halide perovskite QDs

We demonstrate anion-exchange red perovskite QDs  $\text{CsPb(Br/I)}_3$  from pristine  $\text{CsPbBr}_3$  using ammonium-iodine salts, long alkyl-based oleylammonium iodide (OAM-I) and aryl-based aniline hydroiodide (An-HI), for use in highly efficient LEDs.<sup>5)</sup> The anion-exchange  $\text{CsPb(Br/I)}_3$  films exhibit a strong red-shift in their photoluminescence (PL) spectrum from the green emission at 508 nm in the case of the pristine QDs to one in the deep-red region at 649 nm owing to the replacement of  $\text{Br}^-$  anions by  $\text{I}^-$  anions in the perovskite QDs. LEDs formed using the anion-exchange  $\text{CsPb(Br/I)}_3$  based on OAM-I show a remarkable high EQE of more than 20% as well as high color purity, with the Commission Internationale de l'Eclairage (CIE) at (0.72, 0.28), which completely cover BT.2020 color gamut. Similarly, the LEDs formed using the QDs based on An-HI show a peak EQE of 14.1% and CIE coordinates of (0.71, 0.28). Further, they exhibit longer operational stability as compared to that of LEDs formed using the OAM-I-based  $\text{CsPb(Br/I)}_3$ . Therefore, anion exchange perovskite QDs using an ammonium salts is effective approach for highly efficient LEDs.

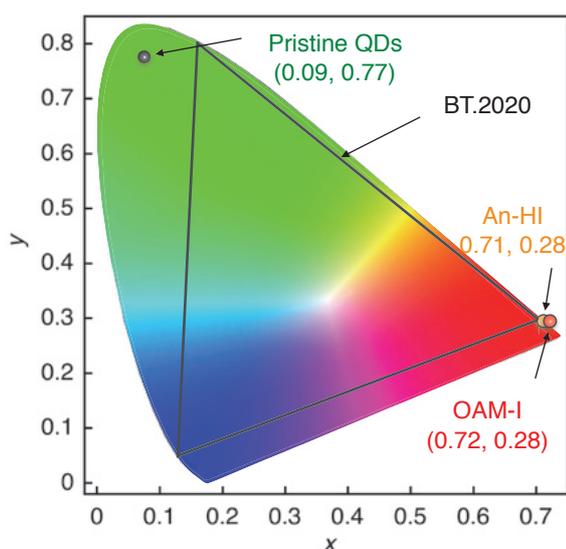


Fig. 6. CIE color coordinate of perovskite QD LEDs.

## 4 CONCLUSIONS

Perovskite QDs based LEDs with high color purity emission spectra in the full visible range have been demonstrated as a good candidate for next-generation light-emitting materials in lighting and display applications. In this paper, we discussed the current approaches to achieve highly efficient perovskite QD-LEDs, hot-injection synthesis method, ligand exchange approaches for surface passivation, and anion exchange for perovskite QD. These post-treatment approaches are promising ways to obtain high quality perovskite QD and high efficiency perovskite QD-LEDs.

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